General Purpose Transistor Medium Power, PNP 80 V, 1 A



BCP53M

The BCP53MTW is designed for general purpose amplifier applications. It is housed in DFN2020–3 offering superior thermal performance. The transistor is ideal for medium–power surface mount applications where board space and reliability are at a premium.

Specification Features

- Wettable Flank Package for Optimal Automated Optical Inspection (AOI)
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS (T_A = $25^{\circ}C$)

Rating	Symbol	Мах	Unit
Collector-Emitter Voltage	V _{CEO}	-80	Vdc
Collector-Base Voltage	V _{CBO}	-100	Vdc
Emitter-Base Voltage	V _{EBO}	-6.0	Vdc
Collector Current – Continuous (Note 1)	Ι _C	1.0	А
Collector Current – Peak (Note 1)	I _{CM}	2.0	А

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

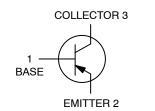
Characteristic	Symbol	Max	Unit
Total Power Dissipation (Note 2) @ T _A = 25°C Derate above 25°C	P _D	1.5	W
Thermal Resistance, Junction-to-Ambient (Note 2)	R_{\thetaJA}	78	°C/W
Total Power Dissipation (Note 3) @ T _A = 25°C Derate above 25°C	P _D	875	mW
Thermal Resistance, Junction-to-Ambient (Note 3)	$R_{\theta JA}$	138	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	−65 to +150	°C

1. Reference SOA Curve

2. Surface-mounted on FR4 board using a 600 mm² pad area and 2 oz. Cu

3. Surface-mounted on FR4 board using a 100 mm² pad area and 2 oz. Cu





MARKING DIAGRAM



3M = Specific Device Code M = Date Code

ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 2 of this data sheet.

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ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

Characteristics	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector-Emitter Breakdown Voltage (I _C = -1 mA, I _B = 0 A)	V _{(BR)CEO}	-80	-	-	V
Collector-Base Breakdown Voltage (I _C = $-100 \ \mu$ A, I _E = 0 A)	V _{(BR)CBO}	-100	-	-	V
Emitter-Base Breakdown Voltage ($I_E = -10 \ \mu A$, $I_C = 0$)	V _{(BR)EBO}	-5	-	-	V
Collector–Base Cutoff Current ($V_{CB} = -30 \text{ V}, I_E = 0$)	I _{CBO}	-	-	-100	nA
Emitter-Base Cutoff Current ($V_{EB} = -5 V$, $I_C = 0$)	I _{EBO}	-	-	-100	nA
ON CHARACTERISTICS (Note 4)					
$ \begin{array}{llllllllllllllllllllllllllllllllllll$	h _{FE}	63 63 63 100 40	- - -	_ 250 160 250 _	
Collector-Emitter Saturation Voltage (I _C = -500 mA, I _B = -50 mA)	V _{CE(sat)}	-	-	-0.50	V
Base-Emitter Saturation Voltage (I _C = -500 mA, I _B = -50 mA)	V _{BE(sat)}	-	-	-2.0	V
Base-Emitter Turn-on Voltage (I _C = -500 mA, V _{CE} = -2.0 V)	V _{BE(on)}	-	-	-1.0	V
SMALL SIGNAL CHARACTERISTICS					
Transition Frequency (I _C = -50 mA, V _{CE} = -5.0 V, f = 100 MHz)	f _T	-	130	-	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	12	-	pF
Input Capacitance ($V_{EB} = -0.5 \text{ Vdc}$, $I_C = 0$, f = 1.0 MHz)	C _{ibo}	-	110	-	pF
Input Impedance (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{ie}	-	5	-	k
Voltage Feedback Ratio (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{re}	-	1	-	X 10 ⁻⁴
Small–Signal Current Gain (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	h _{fe}	_	200	-	-
Output Admittance (I _C = -1.0 mAdc, V _{CE} = -10 Vdc, f = 1.0 kHz)	H _{oe}	-	10	-	μmhos
Noise Figure (I_C = 0.2 mA, V_CE = 5.0 Vdc, R_S = 2.0 k\Omega, f = 1.0 kHz, BW = 200 Hz)	NF	_	0.8	-	dB
SWITCHING CHARACTERISTICS					
Delay Time (V _{CC} = 30 Vdc, I_C = 150 mA, I_{B1} = 15 mA)	t _d	-	18	-	ns
					1

	٩		10		110
Rise Time (V _{CC} = 30 Vdc, I_C = 150 mA, I_{B1} = 15 mA)	t _r	-	32	-	ns
Storage Time (V _{CC} = 30 Vdc, I_C = 150 mA, I_{B1} = 15 mA, I_{B2} = 15 mA)	ts	-	660	-	ns
Fall Time (V _{CC} = 30 Vdc, I_C = 150 mA, I_{B1} = 15 mA, I_{B2} = 15 mA)	t _f	-	50	-	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Condition: Pulse Width = 300 μ s, Duty Cycle \leq 2%.

ORDERING INFORMATION

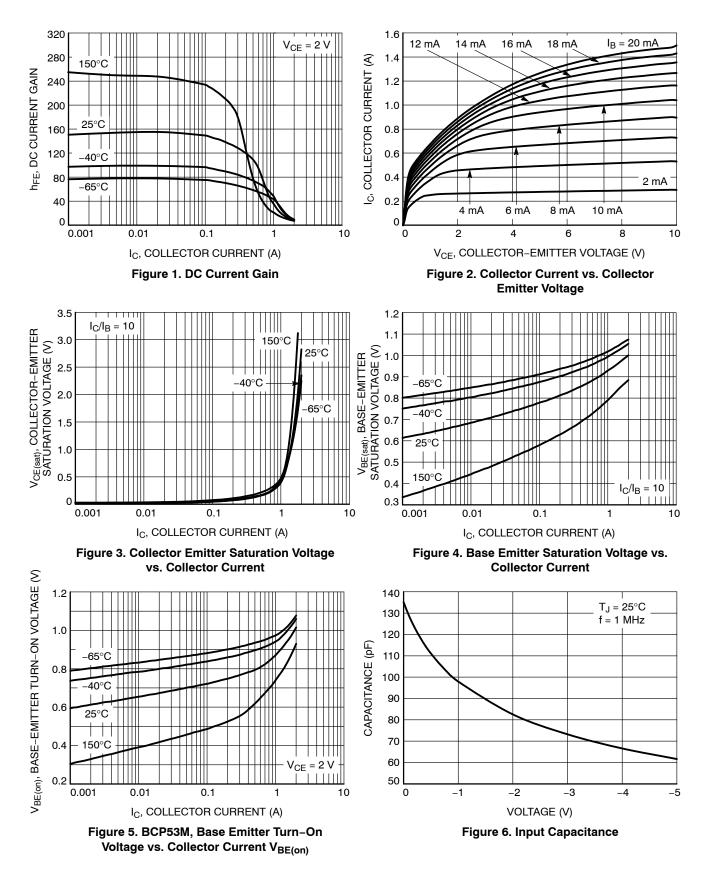
Device	Marking	Package	Shipping [†]			
BCP53MTWG	3M	WDFNW3 (Pb-Free)				
BCP5310MTWG	3N					
BCP5316MTWG	3P		3000 / Tape & Reel			
NSVBCP53MTWG*	3M					
NSVBCP5310MTWG*	3N					
NSVBCP5316MTWG*	3P					

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

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TYPICAL CHARACTERISTICS



BCP53M

TYPICAL CHARACTERISTICS

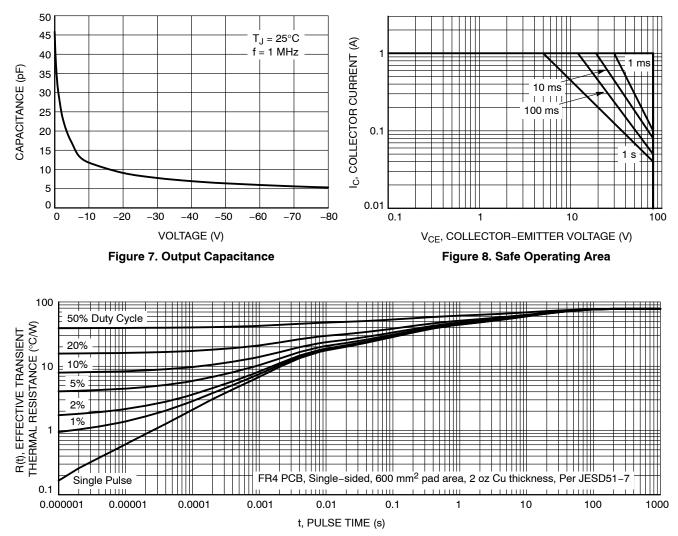


Figure 9. Transient Thermal Impedance from Junction-to-Ambient as a Function of Pulse Duration

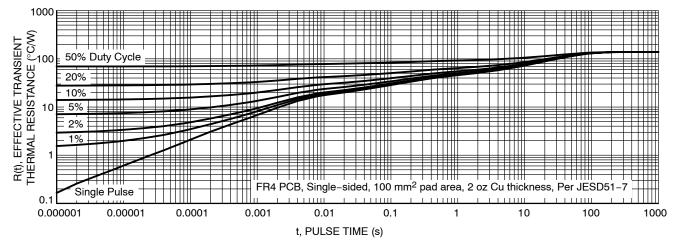
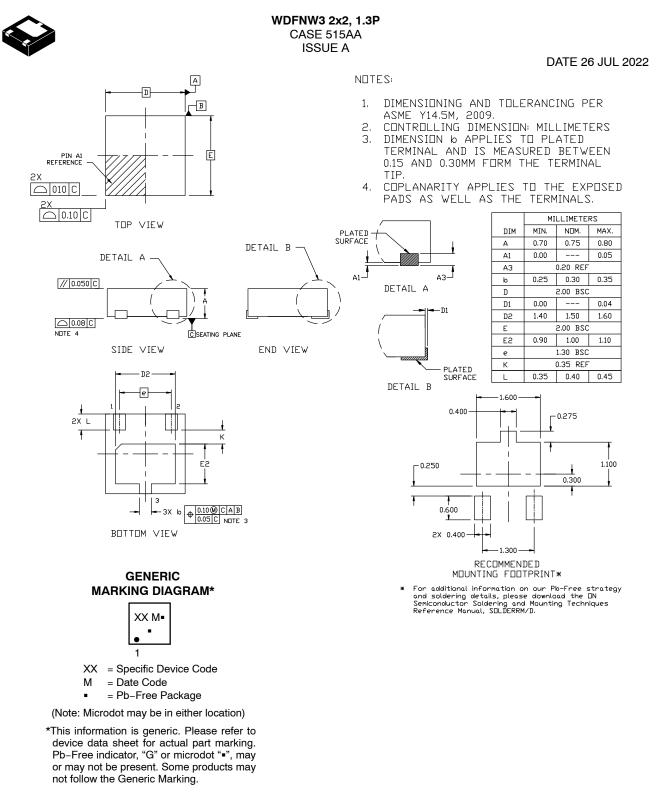


Figure 10. Transient Thermal Impedance from Junction-to-Ambient as a Function of Pulse Duration

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